

# Cascadable Silicon Bipolar MMIC Amplifier

# Technical Data

#### MSA-0611

#### **Features**

- Cascadable 50  $\Omega$  Gain Block
- 3 dB Bandwidth: DC to 0.7 GHz
- **High Gain:** 18.0 dB Typical at 0.5 GHz
- Low Noise Figure: 3.0 dB Typical at 0.5 GHz
- Low Cost Surface Mount Plastic Package
- Tape-and-Reel Packaging Option Available<sup>[1]</sup>

#### Note:

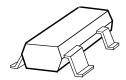
 Refer to PACKAGING section "Tapeand-Reel Packaging for Semiconductor Devices".

#### **Description**

The MSA-0611 is a low cost silicon bipolar Monolithic Microwave Integrated Circuit (MMIC) housed in the surface mount plastic SOT-143 package. This MMIC is designed for use as a general purpose 50  $\Omega$  gain block. Typical applications include narrow and broad band IF and RF amplifiers in commercial and industrial applications.

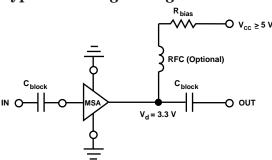
The MSA-series is fabricated using HP's  $10\,\mathrm{GHz}\,\mathrm{f_{T}},25\,\mathrm{GHz}\,\mathrm{f_{MAX}},$  silicon bipolar MMIC process which uses nitride self-alignment, ion implantation, and gold metallization to achieve excellent

#### SOT-143 Package



performance, uniformity and reliability. The use of an external bias resistor for temperature and current stability also allows bias flexibility.

#### **Typical Biasing Configuration**



5965-9584E 6-366

### MSA-0611 Absolute Maximum Ratings

Parameter	Absolute Maximum <sup>[1]</sup>					
Device Current	40 mA					
Power Dissipation <sup>[2,3]</sup>	125 mW					
RF Input Power	+13dBm					
Junction Temperature	150℃					
Storage Temperature	−65 to 150°C					

Thermal Resistance $^{[2,4]}$ :	
$\theta_{\rm jc} = 505$ °C/W	

#### **Notes:**

- 1. Permanent damage may occur if any of these limits are exceeded.
- 2.  $T_{CASE} = 25$ °C.
- 3. Derate at 2.0 mW/°C for  $T_C > 87$ °C.
- 4. See MEASUREMENTS section "Thermal Resistance" for more information.

# Electrical Specifications<sup>[1]</sup>, $T_A = 25$ °C

Symbol	Parameters and Test Conditions:	Units	Min.	Тур.	Max.	
GP	Power Gain $( S_{21} ^2)$	f = 0.1 GHz f = 0.5 GHz	dB	16.0	19.5 18.0	
$\Delta G_{ m P}$	Gain Flatness	f = 0.1  to  0.5  GHz	dB		± 0.8	
f <sub>3 dB</sub>	3 dB Bandwidth		GHz		0.7	
VSWR	Input VSWR	f = 0.1  to  1.5  GHz			1.6:1	
	Output VSWR	f = 0.1  to  1.5  GHz			1.5:1	
NF	$50~\Omega$ Noise Figure	f = 0.5  GHz	dB		3.0	
P <sub>1 dB</sub>	Output Power at 1 dB Gain Compression	f = 0.5  GHz	dBm		2.0	
IP3	Third Order Intercept Point	f = 0.5  GHz	dBm		14.0	
$t_{\mathrm{D}}$	Group Delay	f = 0.5  GHz	psec		225	
Vd	Device Voltage	$T_C = 25$ °C	V	2.6	3.3	4.0
dV/dT	Device Voltage Temperature Coefficient		mV/°C		-8.0	

#### Notes:

# **Part Number Ordering Information**

Part Number	No. of Devices	Container		
MSA-0611-TR1	3000	7" Reel		
MSA-0611-BLK	100	Antistatic Bag		

For more information, see "Tape and Reel Packaging for Semiconductor Devices".

<sup>1.</sup> The recommended operating current range for this device is 12 to 20 mA. Typical gain performance as a function of current is on the following page.

MSA-0611 Typical Scattering Parameters (Z  $_{O}$  = 50  $\Omega,$   $T_{A}$  = 25  $^{\circ}C,$   $I_{d}$  = 16 mA)

Freq. S <sub>11</sub>		$\mathbf{g}_{\mathbf{i}}$ $\mathbf{S}_{11}$			$\mathbf{S_{12}}$				S		
GHz	Mag	Ang	dB	Mag	Ang	dB	Mag	Ang	Mag	Ang	k
0.1	.04	-176	19.6	9.53	170	-23.0	.071	6	.04	<b>-</b> 57	1.07
0.2	.03	-163	19.3	9.25	160	-22.7	.073	10	.07	<b>-</b> 82	1.07
0.3	.03	<b>-</b> 149	18.9	8.79	150	-22.8	.072	14	.09	<b>–</b> 97	1.10
0.4	.04	-132	18.5	8.38	141	-21.9	.080	17	.11	-111	1.07
0.5	.05	-127	18.0	7.96	133	-21.6	.083	21	.13	-122	1.07
0.6	.07	<b>-</b> 123	17.3	7.33	125	-21.2	.087	23	.15	-131	1.07
0.8	.10	-129	16.2	6.46	111	-19.7	.103	25	.17	-147	1.04
1.0	.13	-139	15.0	5.64	98	-19.0	.112	28	.18	-160	1.06
1.5	.22	-164	12.5	4.22	73	-17.1	.139	25	.19	175	1.07
2.0	.31	171	10.1	3.20	53	-16.1	.157	21	.19	160	1.13
2.5	.39	158	8.1	2.55	42	-15.4	.169	22	.20	153	1.19
3.0	.45	144	6.3	2.07	28	-15.0	.178	18	.19	150	1.26
3.5	.50	132	4.7	1.72	16	-14.6	.185	15	.16	152	1.33
4.0	.52	121	3.4	1.48	4	-14.1	.197	11	.14	166	1.37

A model for this device is available in the DEVICE MODELS section.

# Typical Performance, $T_A = 25^{\circ}C$

(unless otherwise noted)

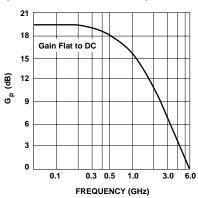


Figure 1. Power Gain vs. Frequency,  $T_A = 25^{\circ}C$ ,  $I_d = 16$  mA.

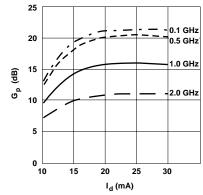


Figure 2. Power Gain vs. Current.

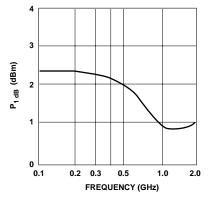


Figure 3. Output Power @ 1 dB Gain Compression vs. Frequency,  $I_{d}=16\ mA.$ 

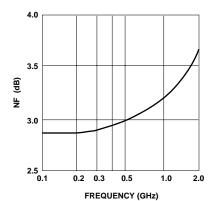
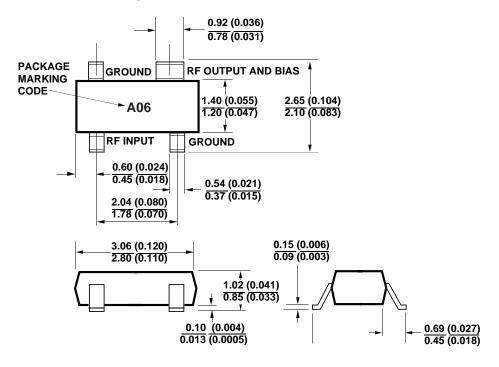


Figure 4. Noise Figure vs. Frequency,  $I_d = 16 \text{ mA}$ .

**SOT-143 Package Dimensions** 



**DIMENSIONS ARE IN MILLIMETERS (INCHES)**